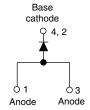


Vishay Semiconductors

Schottky Rectifier, 3.5 A





ו-ח	DΛK	/TO	-252	4 4 1

PRODUCT SUMMARY	PRODUCT SUMMARY						
Package	D-PAK (TO-252AA)						
I _{F(AV)}	3.5 A						
V _R	100 V						
V _F at I _F	See Electrical table						
I _{RM}	4.9 mA at 125 °C						
T _J max.	150 °C						
Diode variation	Single die						
E _{AS}	5 mJ						

FEATURES

- Popular D-PAK outline
- Small foot print, surface mountable



- · Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\text{C}$

DESCRIPTION

The VS-30WQ10FNPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATING	MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS								
I _{F(AV)}	Rectangular waveform	3.5	A								
V_{RRM}		100	V								
I _{FSM}	t _p = 5 μs sine	440	A								
V _F	3 Apk, T _J = 125 °C	0.63	V								
T _J		- 40 to 150	°C								

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-30WQ10FNPbF	UNITS				
Maximum DC reverse voltage	V_{R}	100	V				
Maximum working peak reverse voltage	V_{RWM}	100	V				

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward current See fig. 5	I _{F(AV)}	50 % duty cycle at T _C = 135 °C	3.5					
Maximum peak one cycle non-repetitive surge current	l=o	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	440	Α			
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	70				
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 10 mH		5.0	mJ			
Repetitive avalanche current	I _{AR}	, , ,	Current decaying linearly to zero in 1 µs Frequency limited by T _J maximum V _A = 1.5 x V _R typical					

VS-30WQ10FNPbF

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS						
		3 A	T _{.1} = 25 °C	0.81					
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	6 A	11 = 23 0	0.96	V				
	VFM (')	3 A	T _{.1} = 125 °C	0.63					
		6 A	1j = 125 C	0.74					
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	1	mA				
See fig. 2	'RM '''	T _J = 125 °C	VR = nateu VR	4.9					
Threshold voltage	V _{F(TO)}	T - T movimum		0.48	V				
Forward slope resistance	r _t	$T_J = T_J$ maximum		30.89	mΩ				
Typical junction capacitance	C _T	V _R = 5 V _{DC} (test signal range	100 kHz to 1 MHz), 25 °C	92	pF				
Typical series inductance	L _S	Measured lead to lead 5 mm	5.0	nH					
Maximum voltage rate of change	dV/dt	Rated V _R	_	10 000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C				
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	4.7	°C/W				
Approximate weight			0.3	g				
Approximate weight			0.01	oz.				
Marking device		Case style D-PAK (similar to TO-252AA)	30WC	10FN				

Note

 $^{(1)} \quad \frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$



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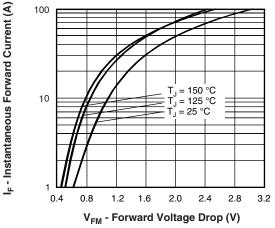


Fig. 1 - Maximum Forward Voltage Drop Characteristics

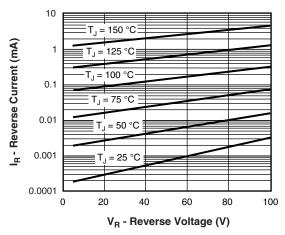


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

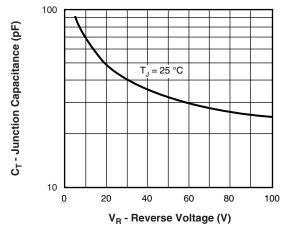


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

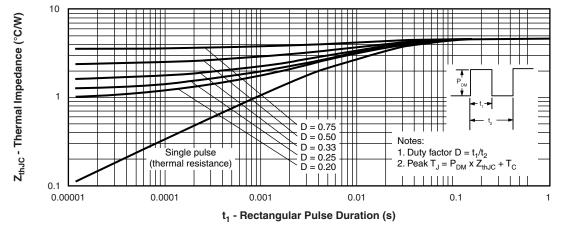
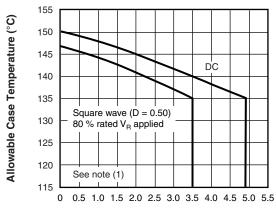


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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Schottky Rectifier, 3.5 A





 $I_{F(AV)}$ - Average Forward Current (A)

Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

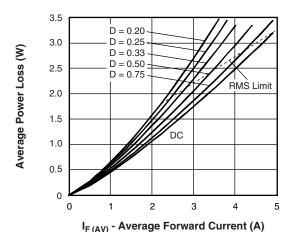


Fig. 6 - Forward Power Loss Characteristics

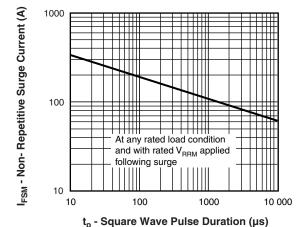


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% rated } V_R \text{ (1 - D); } I_R \text{ (2 - D); } I_R \text{ (3 - D); } I_R \text{ (2 - D); } I_R \text{ (3 - D); } I_R \text{ (3 - D); } I_R \text{ (4 - D);$

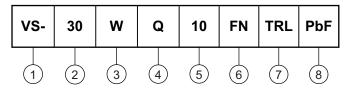


Schottky Rectifier, 3.5 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (3.5 A)

Package identifier:

W = D-PAK

4 - Schottky "Q" series

5 - Voltage rating (10 = 100 V)

6 - FN = TO-252AA (D-PAK)

7 • None = Tube (50 pieces)

• TR = Tape and reel

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

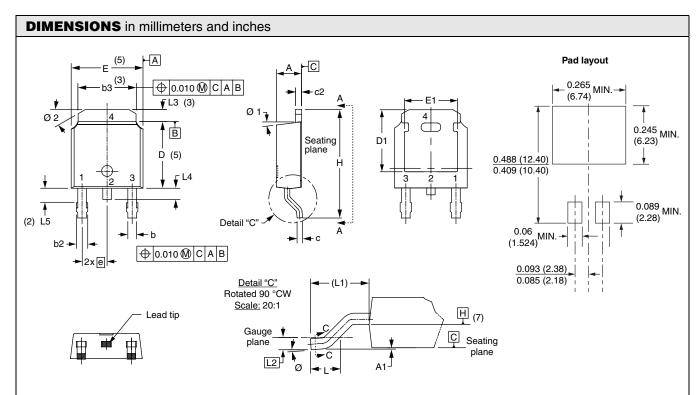
PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95016					
Part marking information	www.vishay.com/doc?95059					
Packaging information	www.vishay.com/doc?95033					



Vishay High Power Products

D-PAK (TO-252AA)



SYMBOL	MILLIM	ETERS	INC	INCHES			
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	2.18	2.39	0.086	0.094			
A1	-	0.13	-	0.005			
b	0.64	0.89	0.025	0.035			
b2	0.76	1.14	0.030	0.045			
b3	4.95	5.46	0.195	0.215	3		
С	0.46	0.61	0.018	0.024			
c2	0.46	0.89	0.018	0.035			
D	5.97	6.22	0.235	0.245	5		
D1	5.21	-	0.205	-	3		
Е	6.35	6.73	0.250	0.265	5		
E1	4.32	-	0.170	-	3		

SYMBOL	MILLIM	ETERS	INC	INCHES			
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
е	2.29 BSC		0.090 BSC				
Н	9.40 10.41		0.370	0.410			
L	1.40	1.78	0.055	0.070			
L1	2.74	BSC	0.108	REF.			
L2	0.51 BSC		0.020				
L3	0.89	1.27	0.035	0.050	3		
L4	-	1.02	-	0.040			
L5	1.14	1.52	0.045	0.060	2		
Ø	0°	10°	0° 10°				
Ø1	0°	0° 15°		15°			
Ø2	25°	35°	25°	35°			

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- $^{(7)}$ Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC outline TO-252AA



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NOTES

3

2

MAX.

0.410

0.070

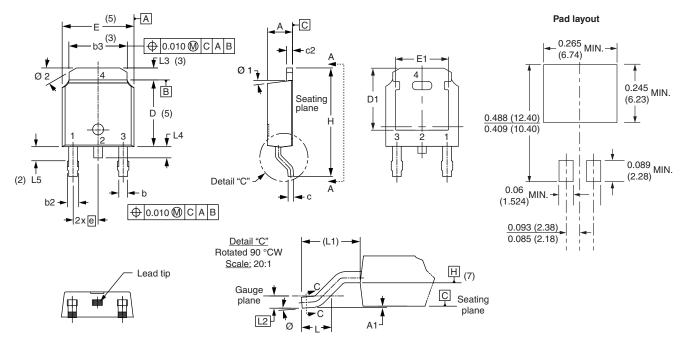
0.050

0.040

0.060

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



Ī	SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		
	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIBUL	MIN.	MAX.	MIN.	MAX
ſ	Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC
ſ	A1	-	0.13		0.005			Н	9.40	10.41	0.370	0.41
Ī	b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.07
Ī	b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.
ſ	b3	4.95	5.46	0.195	0.215	3		L2	0.51 BSC		0.020	BSC
Ī	С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.05
Ī	c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.04
ſ	D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.06
Ī	D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°
ſ	Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°
Ī	E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
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- (7) Datum A and B to be determined at datum plane H
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